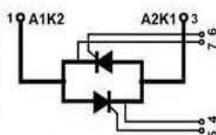
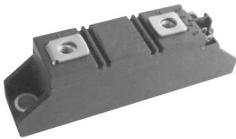


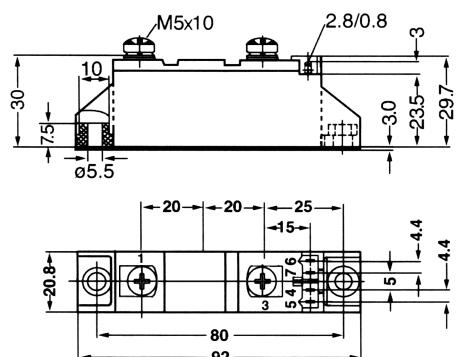
# SSAC70

## Solid State AC Controller(Anti-Parallel Thyristor-Thyristor Modules)



Type	V <sub>RSM</sub> V <sub>DSM</sub> V	V <sub>RRM</sub> V <sub>DRM</sub> V
<b>SSAC70GK08</b>	900	800
<b>SSAC70GK12</b>	1300	1200
<b>SSAC70GK14</b>	1500	1400
<b>SSAC70GK16</b>	1700	1600
<b>SSAC70GK18</b>	1900	1800
<b>SSAC70GK20</b>	2100	2000
<b>SSAC70GK22</b>	2300	2200
<b>SSAC70GK24</b>	2500	2400

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit	
I <sub>TRMS</sub> , I <sub>FRMS</sub> I <sub>TAVM</sub> , I <sub>FAVM</sub>	T <sub>VJ</sub> =T <sub>VJM</sub> T <sub>C</sub> =85°C; 180° sine	180 70	A	
I <sub>TSM</sub> , I <sub>FSM</sub>	T <sub>VJ</sub> =45°C V <sub>R</sub> =0 t=10ms (50Hz), sine t=8.3ms (60Hz), sine	1600 1700	A	
	T <sub>VJ</sub> =T <sub>VJM</sub> V <sub>R</sub> =0 t=10ms(50Hz), sine t=8.3ms(60Hz), sine	1450 1550		
$\int i^2 dt$	T <sub>VJ</sub> =45°C V <sub>R</sub> =0 t=10ms (50Hz), sine t=8.3ms (60Hz), sine	13500 12600	A <sup>2</sup> s	
	T <sub>VJ</sub> =T <sub>VJM</sub> V <sub>R</sub> =0 t=10ms(50Hz), sine t=8.3ms(60Hz), sine	10600 10250		
(di/dt) <sub>cr</sub>	T <sub>VJ</sub> =T <sub>VJM</sub> f=50Hz, t <sub>p</sub> =200us V <sub>D</sub> =2/3V <sub>DRM</sub> I <sub>G</sub> =0.45A dI <sub>G</sub> /dt=0.45A/us	repetitive, I <sub>T</sub> =250A  non repetitive, I <sub>T</sub> =I <sub>TAVM</sub>	150 500	A/us
(dv/dt) <sub>cr</sub>	T <sub>VJ</sub> =T <sub>VJM</sub> ; V <sub>DR</sub> =2/3V <sub>DRM</sub> R <sub>GK</sub> =∞; method 1 (linear voltage rise)	1000	V/us	
P <sub>GM</sub>	T <sub>VJ</sub> =T <sub>VJM</sub> I <sub>T</sub> =I <sub>TAVM</sub> t <sub>p</sub> =30us t <sub>p</sub> =300us	10 5	W	
P <sub>GAV</sub>		0.5	W	
V <sub>RGM</sub>		10	V	
T <sub>VJ</sub> T <sub>VJM</sub> T <sub>stg</sub>		-40...+125 125 -40...+125	°C	
V <sub>ISOL</sub>	50/60Hz, RMS I <sub>ISOL</sub> ≤1mA	t=1min t=1s	3000 3600	V~
M <sub>d</sub>	Mounting torque (M5) Terminal connection torque (M5)	2.5-4.0/22-35 2.5-4.0/22-35	Nm/lb.in.	
Weight	Typical including screws	90	g	

# SSAC70

## Solid State AC Controller(Anti-Parallel Thyristor-Thyristor Modules)

Symbol	Test Conditions	Characteristic Values	Unit
$I_{RRM}, I_{DRM}$	$T_{VJ}=T_{VJM}; V_R=V_{RRM}; V_D=V_{DRM}$	5	mA
$V_T, V_F$	$I_T, I_F=320A; T_{VJ}=25^\circ C$	1.65	V
$V_{TO}$	For power-loss calculations only ( $T_{VJ}=125^\circ C$ )	0.85	V
$r_T$		3.2	$m\Omega$
$V_{GT}$	$V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	1.5 1.6	V
$I_{GT}$	$V_D=6V; T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	100 200	mA
$V_{GD}$	$T_{VJ}=T_{VJM}; V_D=2/3V_{DRM}$	0.2	V
$I_{GD}$		10	mA
$I_L$	$T_{VJ}=25^\circ C; t_p=10\mu s; V_D=6V$ $I_G=0.45A; dI/dt=0.45A/\mu s$	450	mA
$I_H$	$T_{VJ}=25^\circ C; V_D=6V; R_{GK}=\infty$	200	mA
$t_{gd}$	$T_{VJ}=25^\circ C; V_D=1/2V_{DRM}$ $I_G=0.45A; dI/dt=0.45A/\mu s$	2	us
$t_q$	$T_{VJ}=T_{VJM}; I_T=150A; t_p=200\mu s; -dI/dt=10A/\mu s$ $V_R=100V; dv/dt=20V/\mu s; V_D=2/3V_{DRM}$	typ. 185	us
$Q_s$	$T_{VJ}=T_{VJM}; I_T, I_F=50A; -dI/dt=6A/\mu s$	170	uC
$I_{RM}$		45	A
$R_{thJC}$	per thyristor/diode; DC current per module	0.3 0.15	K/W
$R_{thJK}$	per thyristor/diode; DC current per module	0.5 0.25	K/W
$ds$	Creeping distance on surface	12.7	mm
$da$	Strike distance through air	9.6	mm
$a$	Maximum allowable acceleration	50	$m/s^2$

### FEATURES

- \* International standard package
- \* Copper Base Plate with Inter-DCB
- \* Planar passivated chips
- \* Isolation voltage 3600 V~

### APPLICATIONS

- \* DC motor control
- \* Softstart AC motor controller
- \* Light, heat and temperature control

### ADVANTAGES

- \* Space and weight savings
- \* Simple mounting with two screws
- \* Improved temperature and power cycling
- \* Reduced protection circuits



# SSAC70

## Solid State AC Controller(Anti-Parallel Thyristor-Thyristor Modules)

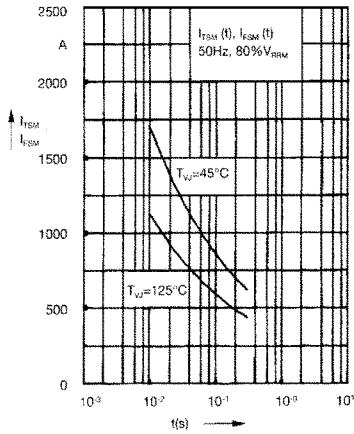


Fig. 1 Surge overload current  
 $I_{TSM}$ ,  $I_{FSM}$ : Crest value,  $t$ : duration

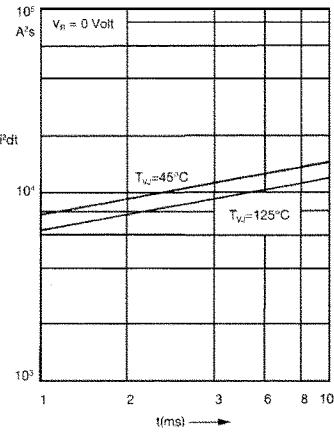


Fig. 2  $\int I^2 dt$  versus time (1-10 ms)

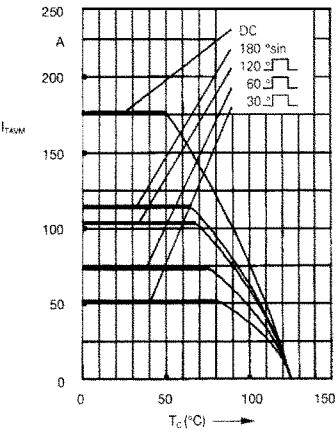


Fig. 2a Maximum forward current  
at case temperature

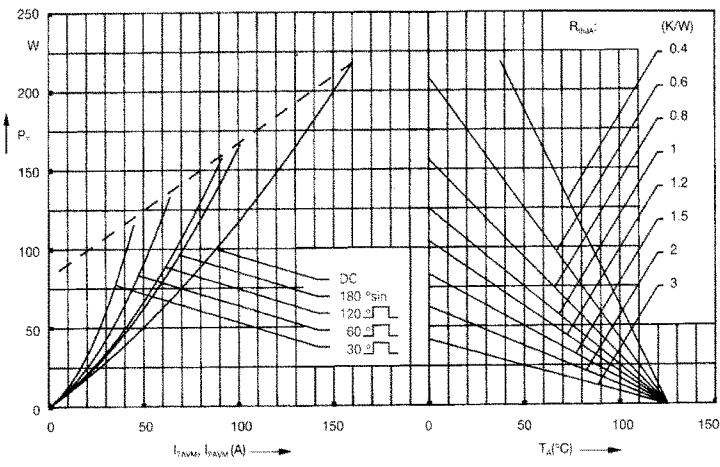


Fig. 3 Power dissipation versus on-state current and ambient temperature  
(per thyristor or diode)

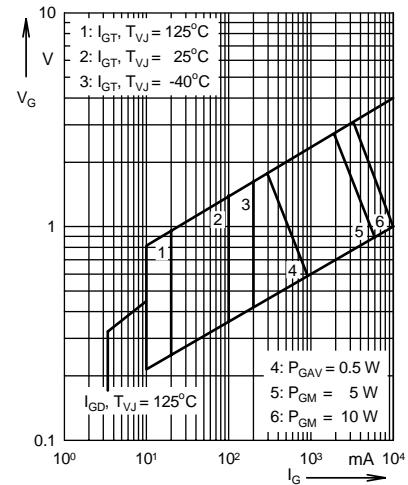


Fig. 4 Gate trigger characteristics

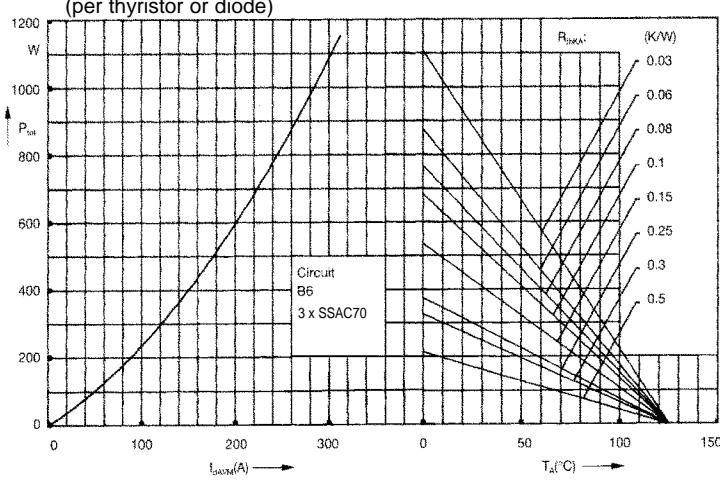


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current  
and ambient temperature

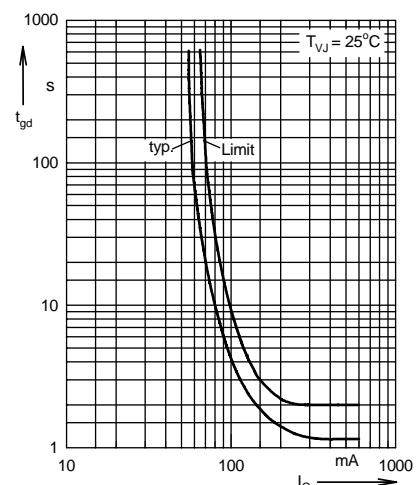


Fig. 6 Gate trigger delay time

# SSAC70

## Solid State AC Controller(Anti-Parallel Thyristor-Thyristor Modules)

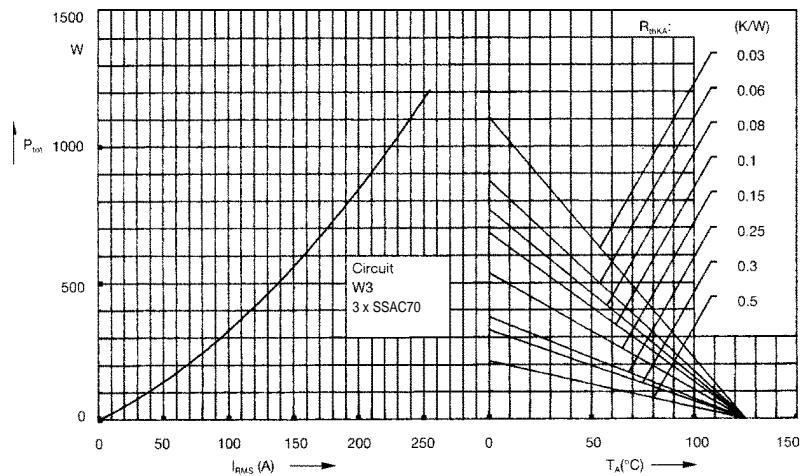


Fig. 7 Three phase AC-controller:  
Power dissipation versus RMS  
output current and ambient  
temperature

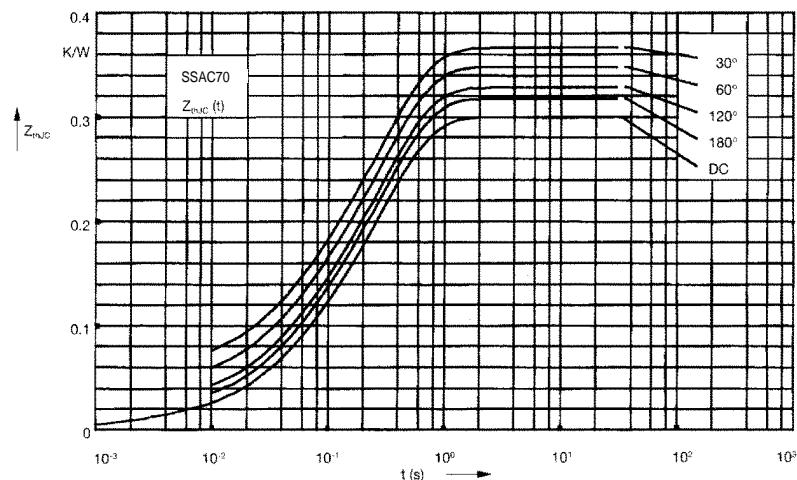


Fig. 8 Transient thermal impedance  
junction to case (per thyristor or  
diode)

$R_{thJC}$  for various conduction angles d:

d	$R_{thJC}$ (K/W)
DC	0.3
180°	0.31
120°	0.33
60°	0.35
30°	0.37

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.008	0.0019
2	0.054	0.047
3	0.238	0.3

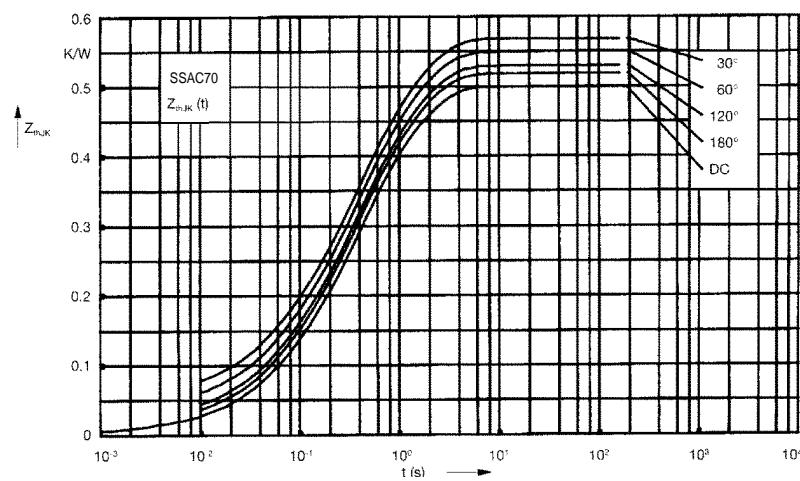


Fig. 9 Transient thermal impedance  
junction to heatsink (per thyristor or  
diode)

$R_{thJK}$  for various conduction angles d:

d	$R_{thJK}$ (K/W)
DC	0.5
180°	0.51
120°	0.53
60°	0.55
30°	0.57

Constants for  $Z_{thJK}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.008	0.0019
2	0.054	0.047
3	0.238	0.3
4	0.2	1.25